

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of : Customer Number: 53080
: :
Tohru SAITO, et al. : Confirmation Number: 8353
: :
Application No.: 10/588,605 : Group Art Unit: 2818
: :
Filed: August 07, 2006 : Examiner: HUYNH, ANDY
: :
For: SEMICONDUCTOR NANOWIRE AND SEMICONDUCTOR DEVICE INCLUDING
THE NANOWIRE

REQUEST FOR CERTIFICATE OF CORRECTION UNDER 37 CFR 1.322

Mail Stop Certificate of Correction
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

In reviewing the above-identified patent, a printing error was discovered therein requiring correction in order to conform the Official Record in the application.

The error noted is set forth on the attached copy of form PTO-1050 Rev. 2-93 in the manner required by the Commissioner's Notice.

Specifically, In Item "(56) References Cited", under "FOREIGN PATENT DOCUMENTS", the reference "WO WO 02/080280 A1 10/2002" should be listed as --WO 02/080280 A1 10/2002--; the reference "WO WO 03/046536 A1 6/2003" should be listed as --WO 03/046536 A1 6/2003--; the reference "WO WO 2004/032191 A2 4/2004" should be listed as --WO 2004/032191 A2 4/2004--; and the reference "WO WO 2004/032193 A2 4/2004" should be listed as --WO 2004/032193 A2 4/2004--. As can be seen on the attached 1449 Form filed August 7, 2006, the correct information was provided.

The change requested herein occurred as a result of printing the Letters Patent and the Certificate should be issued without expense under Rule 322 of the Rules of Practice. Accordingly, Applicants request issuance of the Certificate of Correction.

Please charge any shortage in fees due in connection with the filing of this paper to Deposit Account 500417 and please credit any excess fees to such deposit account.

Respectfully submitted,

McDERMOTT WILL & EMERY LLP

Michael E. Fogarty
Registration No. 36,139

**Please recognize our Customer No. 53080
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Date: July 15, 2010

Receipt date: 08/07/2006

AP20 Rec'd PCT/PTO 05 AUG 2006

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INFORMATION DISCLOSURE
CITATION IN AN
APPLICATION

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(PTO-1449)

APPLICANT
Tohru SAITO, et al.FILING DATE
August 07, 2006GROUP
Not Yet Assigned

U.S. PATENT DOCUMENTS

EXAMINER'S INITIALS	CITE NO.	Document Number Number-Kind Code ₂ (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
/A.H./		US 2002/0130311 A1	09/19/2002	Lieber et al.	Corresponds to JP 2004-507104
/A.H./		US 2002/0163079 A1	11/07/2002	Awano	
/A.H./		US 2003/0089899 A1	05/15/2003	Lieber et al.	
/A.H./		US 2004/0005723 A1	01/08/2004	Empedocles et al.	
/A.H./		US 2005/0142766 A1	06/30/2005	Harelund et al.	

FOREIGN PATENT DOCUMENTS

EXAMINER'S INITIALS	CITE NO.	Foreign Patent Document Country Code ₂ -Number & Kind Codes (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines Where Relevant Figures Appear	Translation Yes No
/A.H./		JP 2004-507104	03/04/2004	PRESIDENT AND FELLOWS OF HARVARD COLLEGE	Corresponds to US 2002/0130311 A1	English Abstract Only
/A.H./		JP 2005-510711	04/21/2005	SONY INTERNATIONAL	Corresponds to WO 03/046536 A1	English Abstract Only
/A.H./		WO 03/046536 A1	06/05/2003	SONY INTERNATIONAL	Corresponds to JP 2005-510711	English Abstract Only
/A.H./		WO 2004/032191 A2	04/15/2004	NANOSYS, INC.		English Abstract Only
/A.H./		WO 2004/032193 A2	04/15/2004	NANOSYS, INC.		English Abstract Only
/A.H./		WO 02/080280 A1	10/10/2002	THE REGENTS OF THE UNIVERSITY OF CALIFORNIA		English Abstract Only

OTHER ART (Including Author, Title, Date, Pertinent Pages, Etc.)

EXAMINER'S INITIALS	CITE NO.	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.
/A.H./		Duan, X., et al. "High-Performance Thin-Film Transistors Using Semiconductor Nanowires and Nanoribbons," Nature, Vol. 425, September 18 2003, pp. 274-278.
/A.H./		Chen, X., et al. "Electron Mobility Enhancement in Strained SiGe Vertical n-type Metal-oxide-semiconductor Field-effect Transistors," American Institute of Physics, Vol. 78, No. 3, January 15, 2001, pp. 377-379.

EXAMINER
/Andy Huynh/ (04/02/2009)DATE CONSIDERED
10/07/2006

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

1 Applicant's unique citation designation number (optional). 2 Applicant is to place a check mark here if English language Translation is attached.

**UNITED STATES PATENT AND TRADEMARK OFFICE
CERTIFICATE OF CORRECTION**

PATENT NO : 7629629

Page 1 of 1

APPLICATION NO. : 10/588,605

ISSUE DATE : December 08, 2009

INVENTOR(S) : Tohru SAITO, et al.

It is certified that an error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

In Item "(56) References Cited", under "FOREIGN PATENT DOCUMENTS",
the reference "WO WO 02/080280 A1 10/2002" should be listed as --WO 02/080280 A1 10/2002--;
the reference "WO WO 03/046536 A1 6/2003" should be listed as --WO 03/046536 A1 6/2003--;
the reference "WO WO 2004/032191 A2 4/2004" should be listed as --WO 2004/032191 A2 4/2004--;
and
the reference "WO WO 2004/032193 A2 4/2004" should be listed as --WO 2004/032193 A2 4/2004--.

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This collection of information is required by 37 CFR 1.322, 1.323, and 1.324. The information is required to obtain or retain a benefit by the public which is to file (and by the USPTO to process) an application. Confidentiality is governed by 35 U.S.C. 122 and 37 CFR 1.14. This collection is estimated to take 1.0 hour to complete, including gathering, preparing, and submitting the completed application form to the USPTO. Time will vary depending upon the individual case. Any comments on the amount of time you require to complete this form and/or suggestions for reducing this burden, should be sent to the Chief Information Officer, U.S. Patent and Trademark Office, U.S.